OPB822S, OPB822SD OPB826S, OPB826SD

Features:

- Non-contact switching
- Single or double apertures for high resolution
- Choice of slot widths
- Choice of side-by-side or over/under dual channels
- Choice of electrical outputs



Description:

Each **OPB822** and **OPB826** slotted switch consists of two infrared emitting diodes and two NPN silicon phototransistors mounted on opposite sides of a 0.090" (2.29 mm) wide slot **(OPB822)** or a 0.100" (2.54 mm) wide slot **(OPB826)**.

OPB822 uses an side-by-side mounting configuration, while **OPB826** uses an over/under mounting configuration. **OPB822S** has 0.01" by 0.04" (0.25 mm x 1.02 mm) apertures in front of both phototransistors while the **OPB822SD** has the aperture in front of both phototransistors and both emitters. The **OPB826S** has 0.04" by 0.04" (1.02 mm x 1.02 mm) apertures in front of both phototransistors while the **OPB826SD** has the aperture in front of both phototransistors and both emitters.

Dual channels enable direction of travel sensing, with the low-cost plastic housing reduces possible interference from ambient light and provides protection from dust and dirt.

Phototransistor switching occurs when an opaque object passes through the device slot.

For information on encoder design, see Application Bulletin 203 at:

Custom electrical, wire and cabling and

connectors are available. Contact your local representative or OPTEK for more information.

Applications:

- Encoders
- Non-contact object sensing
- Assembly line automation
- Machine automation
- Equipment security
- Machine safety

	LED		Slot	Aperture	Lead
Part	Peak		Width /	Emitter/	Length /
Number	Wavelength	Sensor	Depth	Sensor	Spacing
OPB822S				None /	
UPD0223	Dual	Dual	0.09" /	0.01"	0.35" /
OPB822SD	935 nm	Transistor	0.30"	0.01" /	0.30"
				0.01"	
OPB826S	Dual	Dual	0.10" /	NA / 0.04"	0.20" /
OPB826SD	890 nm	Transistor	0.42"	0.04" /	0.74"
UPD6203D				0.04"	• •



General Note

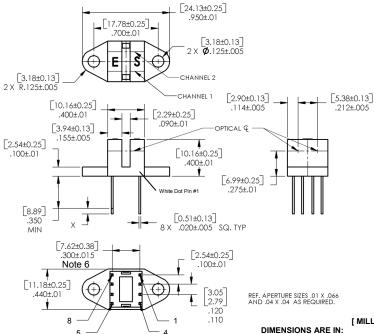
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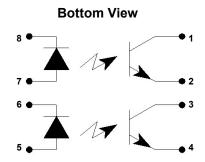
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OPB822S, OPB822SD OPB826S, OPB826SD



OPB822



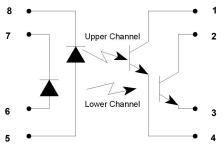


Pin #	Description	Pin #	Description
8	Cathode-1	1	Collector-1
7	Anode-1	2	Emitter-1
6	Cathode-2	3	Collector-2
5	Anode-2	4	Emitter-2

Bottom View

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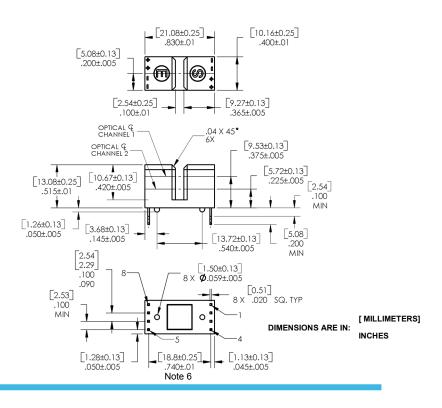


Pin #	Description	Pin #	Description
8	Cathode-1	1	Collector-1
7	Cathode-2	2	Collector-2
6	Anode-2	3	Emitter-2
5	Anode-1	4	Emitter-1



[MILLIMETERS] INCHES

OPB826



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OPB822S, OPB822SD



OPB826S, OPB826SD

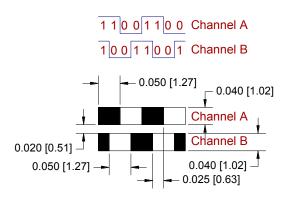
Absolute Maximum Ratings (T_A = 25° C unless otherwise noted)

Storage & Operating Temperature Range	-40° C to +85° C
Lead Soldering Temperature [1/16 inch (1.6mm) from the case for 5 sec. with soldering iron] $^{(1)}$	240°C
Input Diode	
Forward DC Current OPB822S, OPB822SD OPB826S, OPB826SD	50 mA 40 mA
Peak Forward Current (1 µs pulse width, 300 pps)	1 A
Reverse DC Voltage	2 V
Power Dissipation ⁽²⁾	100 mW
Output Phototransistor	
Collector-Emitter Voltage	30 V
Emitter-Collector Voltage	5 V
Collector DC Current	30 mA
Power Dissipation ⁽²⁾	100 mW

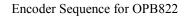
Notes:

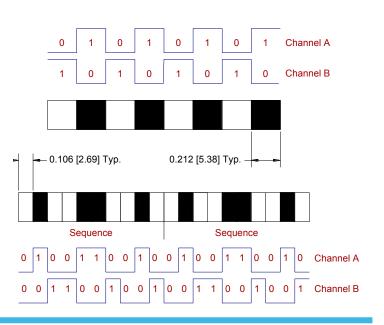
- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
- (2) Derate linearly 1.67 mW/°C above 25° C.
- (3) Methanol or isopropanol are recommended as cleaning agents. Plastic housing is soluble in chlorinated hydrocarbons and ketones. Spray and wipe; do not submerge.
- (4) Derate linearly 3.33 mW/°C above 25° C.
- (5) All parameters tested using pulse techniques.
- (6) Feature controlled at body.

Encoder Sequence for OPB826



For information on encoder design, see Application Bulletin 203 at: http://www.optekinc.com/pdf/App_Note_203.pdf





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OPB822S, OPB822SD



OPB826S, OPB826SD

Electrical Characteristics (OPB822, OPB826) (T_A = 25°C unless otherwise noted) SYMBOL PARAMETER MIN TYP MAX UNITS **TEST CONDITIONS** Input Diode (see OP140 for OPB822 or OP266 for OPB826 for additional information) Forward Voltage 1.7 V $I_{F} = 20 \text{ mA}$ V_{F} -- I_R **Reverse Current** --100 μΑ $V_R = 2 V$ Output Phototransistor (see OP550 for OPB822 or OP506 for OPB826 for additional information) V_{(BR)(CEO)} Collector-Emitter Breakdown Voltage 30 -_ V $I_c = 1 \text{ mA}$ Emitter-Collector Breakdown Voltage ٧ V_{(BR)(ECO)} 5 -- $I_{E} = 100 \ \mu A$ Collector-Emitter Leakage Current 100 $V_{CE} = 10 \text{ V}, I_F = 0, E_E = 0$ nΑ I_{CEO} --Coupled **On-State Collector Current OPB822S** 250 μΑ $V_{CE} = 5 V, I_F = 20 mA$ -I_{C(ON)} OPB822SD 100 -_ μΑ $V_{CE} = 5 V, I_F = 20 mA$ **OPB826S** 250 μΑ $V_{CF} = 10 V$, $I_F = 20 mA$ -OPB826SD 100 $V_{CF} = 10 V, I_F = 20 mA$ μΑ -Collector-Emitter Saturation Voltage OPB822S 0.4 V $I_{c} = 125 \ \mu A$, $I_{F} = 20 \ mA$ - $V_{CE(SAT)}$ OPB822SD V $I_{c} = 50 \ \mu A$, $I_{F} = 20 \ mA$ -0.4 **OPB826S** 0.4 V $I_{c} = 125 \ \mu A$, $I_{F} = 20 \ mA$ _ -OPB826SD _ -0.4 V $I_c = 50 \ \mu A$, $I_F = 20 \ mA$ Crosstalk OPB822D, OPB822SD 250 μΑ $I_{F1} = 0 \text{ mA}, I_{F2} = 20 \text{ mA}, V_{CE} = 10 \text{ V}$ I_{CX1} **OPB826S** 20 _ _ OPB826SD 10 -

Notes:

(1) All parameters tested using pulse techniques.

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